

1. General description

Silicon Carbide Schottky diode in a TO263 (D2PAK) plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- Highly stable switching performance
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

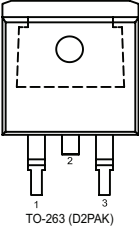
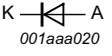
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute maximum rating							
V_{RRM}	repetitive peak reverse voltage			650			V
I_F	continuous forward current	$T_{mb} \leq 138\text{ °C}$, DC; Fig. 2		10			A
T_j	junction temperature			-55 to 175			°C
Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V_F	forward voltage	$I_F = 10\text{ A}$; $T_j = 25\text{ °C}$; Fig. 5		-	1.45	1.70	V
		$I_F = 10\text{ A}$; $T_j = 150\text{ °C}$; Fig. 5		-	1.80	2.20	V
Dynamic characteristics							
Q_r	recovered charge	$I_F = 10\text{ A}$; $di_F/dt = 500\text{ A}/\mu\text{s}$; $V_R = 400\text{ V}$; $T_j = 25\text{ °C}$; Fig. 7		-	14.5	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		
2	K	cathode [1]		
3	A	anode		
mb	K	mounting base; connected to cathode		

[1] It is not possible to connect to pin 2 of the TO263 package.

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC5D10650B	TO263	WNSC5D10650B6J	Reel	800	TO263N	26-Sep-2016

7. Marking

Table 4. Marking codes

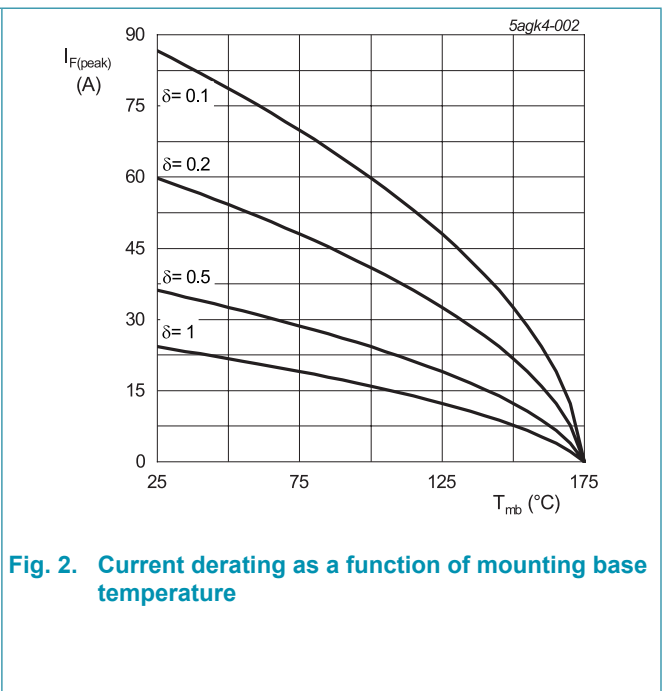
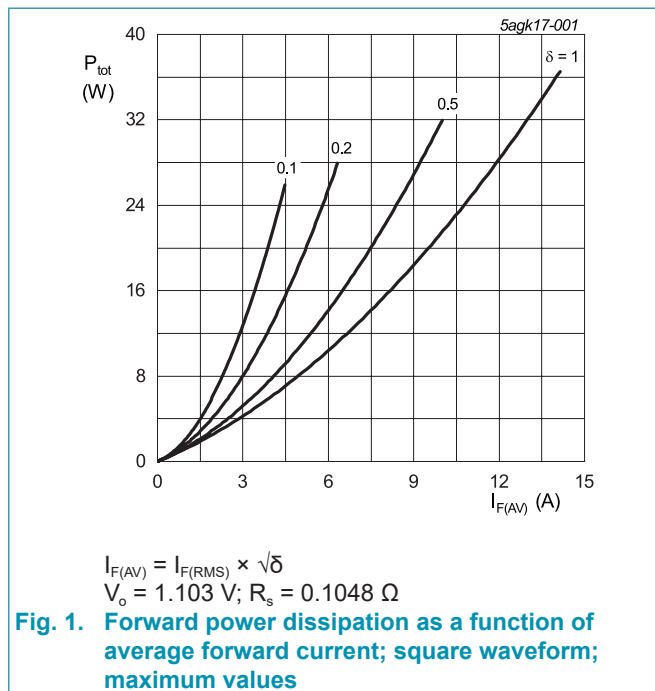
Type number	Marking codes
WNSC5D10650B	WNSC5D 10650B

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			650	V
V_{RWM}	crest working reverse voltage			650	V
V_R	reverse voltage	DC		650	V
I_F	continuous forward current	$T_{mb} \leq 138\text{ °C}$, DC; Fig. 2		10	A
		$T_{mb} \leq 125\text{ °C}$, DC; Fig. 2		12	A
		$T_{mb} \leq 25\text{ °C}$, DC; Fig. 2		24	A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25\ \mu\text{s}$; $T_{mb} \leq 125\text{ °C}$; square-wave pulse		19	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10\text{ ms}$; $T_{j(\text{init})} = 25\text{ °C}$; sine-wave pulse		60	A
		$t_p = 10\ \mu\text{s}$; $T_{j(\text{init})} = 25\text{ °C}$; square-wave pulse		550	A
I^2t	I^2t for fusing	$t_p = 10\text{ ms}$; $T_{j(\text{init})} = 25\text{ °C}$; sine-wave pulse		18	A ² s
T_{stg}	storage temperature			-55 to 175	°C
T_j	junction temperature			-55 to 175	°C



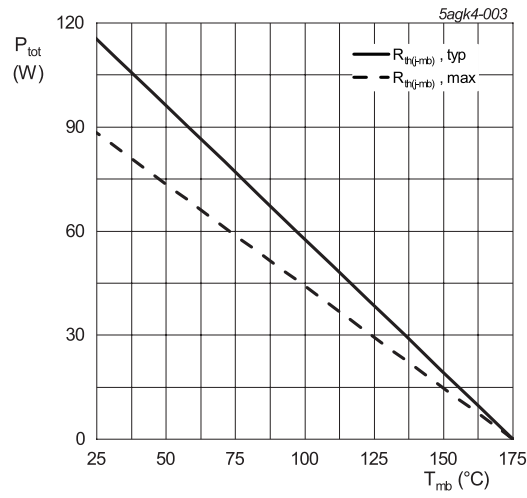


Fig. 3. Total power dissipation as a function of mounting base temperature

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 4		-	1.3	1.7	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W

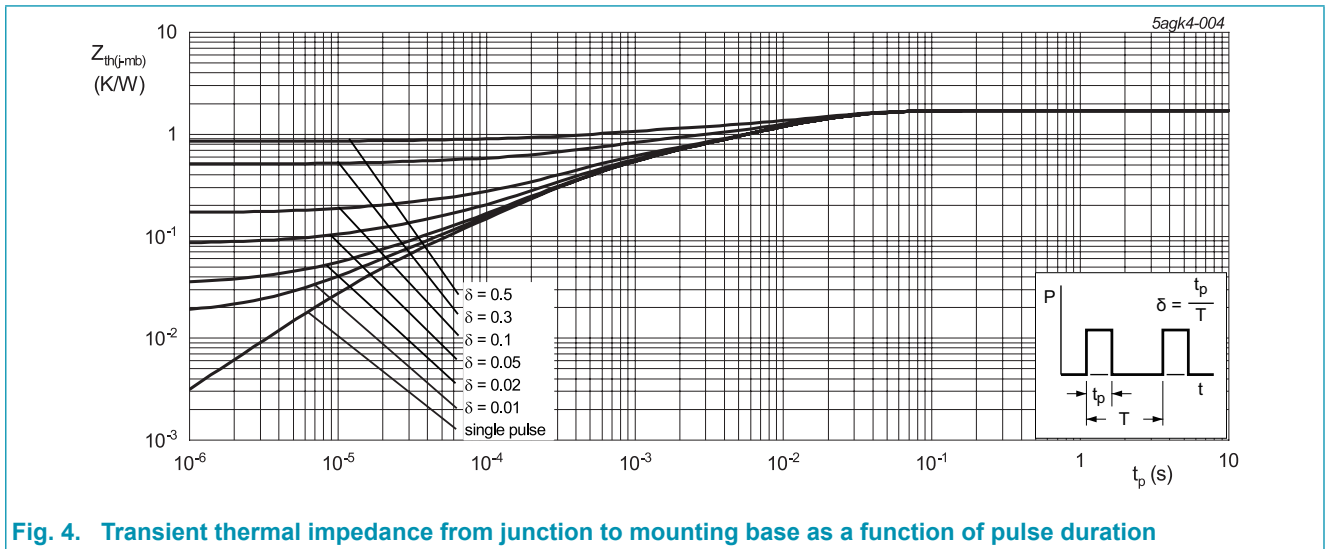
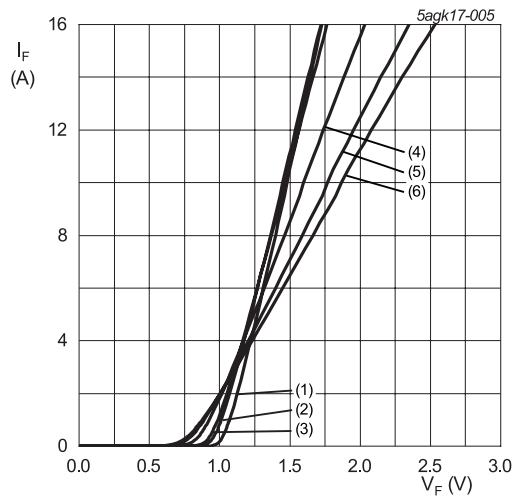


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V_F	forward current	$I_F = 10 \text{ A}; T_J = 25 \text{ }^\circ\text{C}; \text{Fig. 5}$		-	1.45	1.70	V
		$I_F = 10 \text{ A}; T_J = 150 \text{ }^\circ\text{C}; \text{Fig. 5}$		-	1.80	2.20	V
		$I_F = 10 \text{ A}; T_J = 175 \text{ }^\circ\text{C}; \text{Fig. 5}$		-	2.00	2.30	V
I_R	reverse current	$V_R = 650 \text{ V}; T_J = 25 \text{ }^\circ\text{C}; \text{Fig. 6}$		-	0.5	50	μA
		$V_R = 650 \text{ V}; T_J = 175 \text{ }^\circ\text{C}; \text{Fig. 6}$		-	25	250	μA
Dynamic characteristics							
Q_r	recovered charge	$I_F = 10 \text{ A}; V_R = 400 \text{ V}; di_F/dt = 500 \text{ A}/\mu\text{s}; T_J = 25 \text{ }^\circ\text{C}; \text{Fig. 7}$		-	14.5	-	nC
C_d	diode capacitance	$f = 1 \text{ MHz}; V_R = 1 \text{ V}; T_J = 25 \text{ }^\circ\text{C}$		-	323	-	pF
		$f = 1 \text{ MHz}; V_R = 300 \text{ V}; T_J = 25 \text{ }^\circ\text{C}$		-	38	-	pF
		$f = 1 \text{ MHz}; V_R = 600 \text{ V}; T_J = 25 \text{ }^\circ\text{C}$		-	35	-	pF
E_{as}	non-repetitive avalanche energy	$I_R = 4.9 \text{ A}; T_{j(\text{init})} = 25 \text{ }^\circ\text{C}; L = 5 \text{ mH}$		60	-	-	mJ



$V_o = 1.103 \text{ V}; R_s = 0.1048 \text{ } \Omega$
 (1) $T_J = -55 \text{ }^\circ\text{C}$; typical values
 (2) $T_J = 0 \text{ }^\circ\text{C}$; typical values
 (3) $T_J = 25 \text{ }^\circ\text{C}$; typical values
 (4) $T_J = 100 \text{ }^\circ\text{C}$; typical values
 (5) $T_J = 150 \text{ }^\circ\text{C}$; typical values
 (6) $T_J = 175 \text{ }^\circ\text{C}$; typical values

Fig. 5. Forward current as a function of forward voltage; typical values

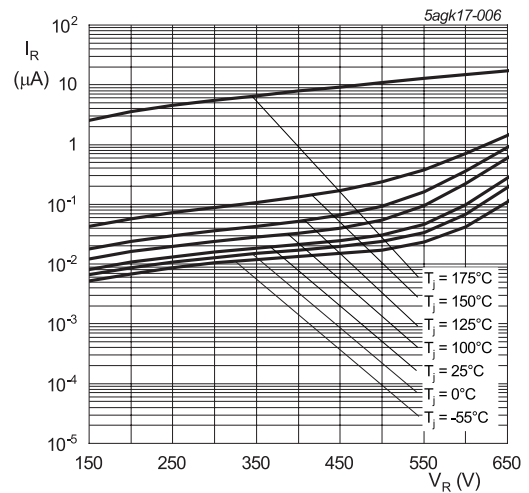


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value

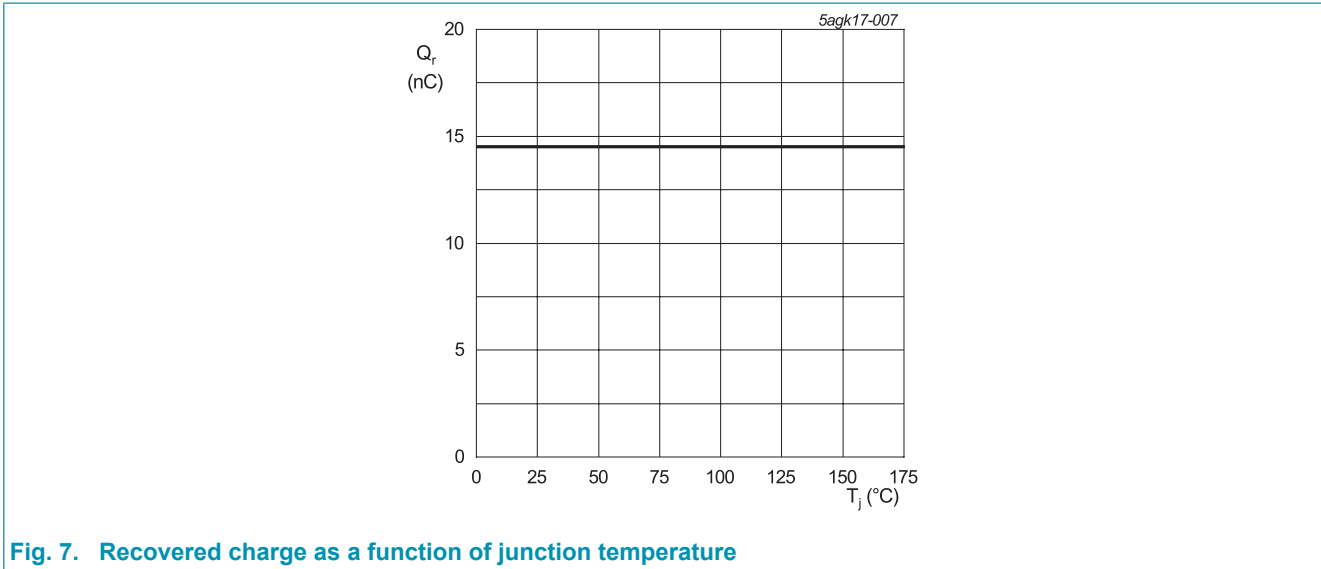
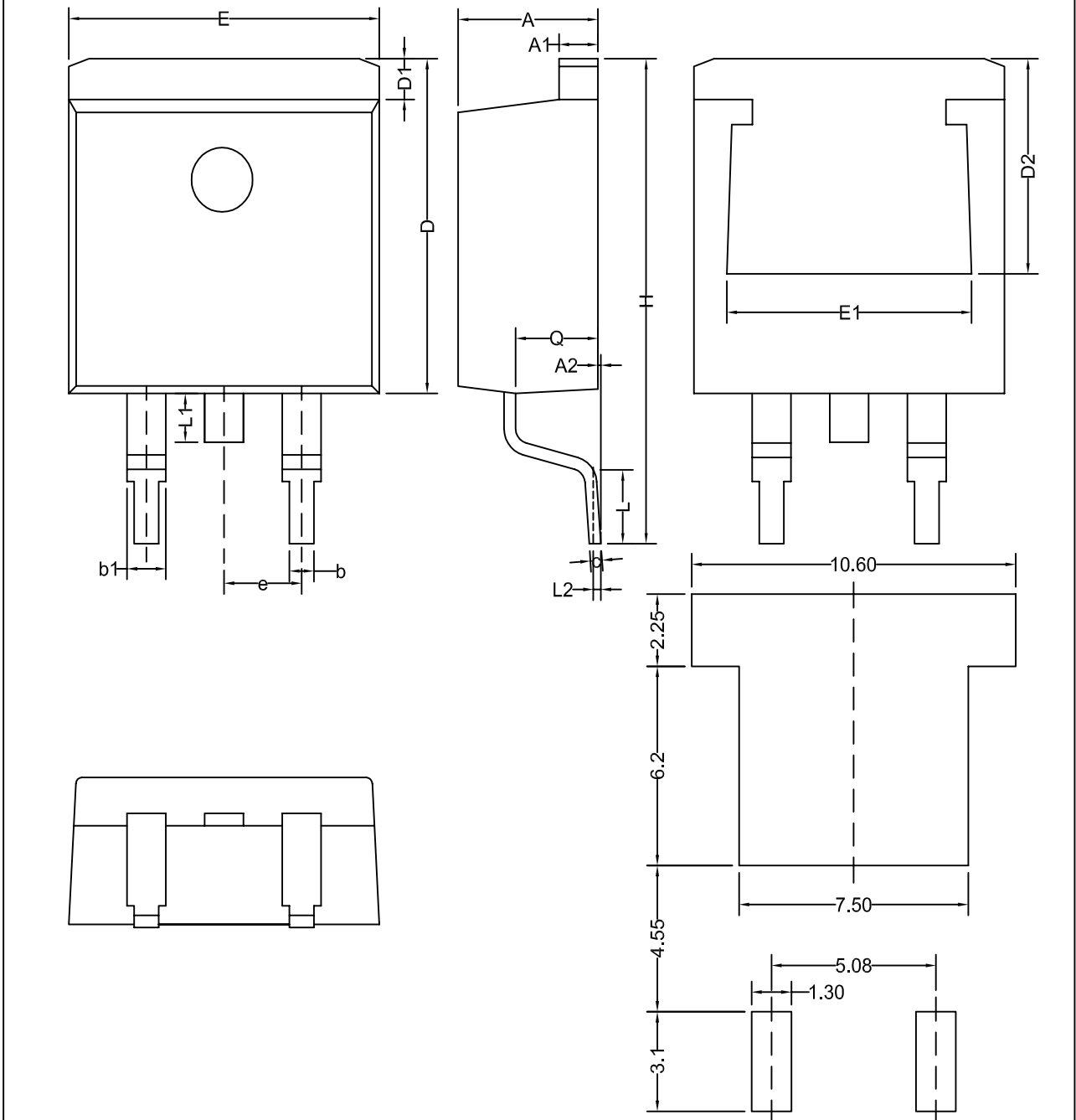


Fig. 7. Recovered charge as a function of junction temperature

11. Package outline

Plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) TO263



Recommended Footprint

Unit	A	A1	A2	b	b1	c	D	D1	D2	e	E	E1	H	L	L1	L2	Q
min	4.10	1.22	0.00	0.60	1.05	0.34	---	1.20	6.60	---	9.70	7.80	14.80	2.10	---	---	2.20
max	4.70	1.40	0.25	0.90	1.45	0.64	11.00	1.60	---	2.54 (BSC)	10.30	---	15.80	2.90	1.75	0.25 (BSC)	2.79

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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